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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO
09/922,671	08/07/2001	Shigeki Furuya	60188-084	1398
75	590 05/09/2003			
Jack Q. Lever, Jr. McDERMOTT, WILL & EMERY 600 Thirteenth Street, N.W.			EXAMINER	
			WARREN, MATTHEW E	
Washington, Do	C 20005-3096		ART UNIT	PAPER NUMBER
			2815	

Please find below and/or attached an Office communication concerning this application or proceeding.

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		Application No.	Applicant(s)	10				
Office Action Summary		09/922,671	FURUYA ET AL.					
		Examiner	Art Unit					
		Matthew E. Warren	2815					
The MAILING DATE of this communication appears on the cover sh t with the correspond nce address Period for Reply								
A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) FROM THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a reply within the statutory minimum of thirty (30) days will be considered timely. - If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication. - Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). - Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b). Status								
1) 🖂	Responsive to communication(s) filed on 14 l	March 2003 .						
2a)□		is action is non-final.						
3) 🗆	Since this application is in condition for allowa		matters, prosecution as to t	he merits is				
closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213. Disposition of Claims								
4) Claim(s) <u>22-41</u> is/are pending in the application.								
4a) Of the above claim(s) is/are withdrawn from consideration.								
5)⊠ Claim(s) <u>34-40</u> is/are allowed.								
6)⊠ Claim(s) <u>22-33 and 41</u> is/are rejected.								
7) 🗌	7) Claim(s) is/are objected to.							
8) Claim(s) are subject to restriction and/or election requirement. Application Papers								
9) ☐ The specification is objected to by the Examiner.								
10) The drawing(s) filed on is/are: a) accepted or b) dispected to by the Examiner.								
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).								
11)☐ The proposed drawing correction filed on is: a)☐ approved b)☐ disapproved by the Examiner.								
If approved, corrected drawings are required in reply to this Office action.								
12) The oath or declaration is objected to by the Examiner.								
Priority under 35 U.S.C. §§ 119 and 120								
13) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).								
a) All b) Some * c) None of:								
	1. Certified copies of the priority documents have been received.							
2. Certified copies of the priority documents have been received in Application No								
 3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)). * See the attached detailed Office action for a list of the certified copies not received. 								
14) 🗌 A	cknowledgment is made of a claim for domesti	ic priority under 35 U.S	S.C. § 119(e) (to a provisiona	al application).				
 a) ☐ The translation of the foreign language provisional application has been received. 15)☐ Acknowledgment is made of a claim for domestic priority under 35 U.S.C. §§ 120 and/or 121. 								
Attachment(s)								
1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948) 3) Information Disclosure Statement(s) (PTO-1449) Paper No(s)								
J.S. Patent and Tr	rademark Office							

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DETAILED ACTION

This Office Action is in response to the RCE and Amendment filed on March 14, 2003.

Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.

Claims 22 and 23 are rejected under 35 U.S.C. 102(e) as being anticipated by Nagai et al. (US 6,114,767 B1).

Nagai et al. shows (figs 9 and 11E) a CMOS basic cell comprising an N-channel transistor region and a P-channel transistor region isolated from each other by an insulating film (3 in top view of fig. 9) on a substrate (1). An interconnect is (12a) is connected to one of the N-channel or P-channel transistors through a contact hole. An interconnect pattern (15a) exists between the two transistors and is formed in an uppermost interconnect layer (of layer 13). The interconnect also extends along a direction horizontal to a boundary between the N-channel transistor region and the P-channel transistor region.

Claim 41 is rejected under 35 U.S.C. 102(e) as being anticipated by Arima et al. (US 6,091,088).

Arima et al. shows (fig. 5B) a semiconductor device including a plurality of basic cells arranged in the same direction, wherein each cell is composed of a an N-channel and P-channel transistor. A gate (11) of one of the N-channel transistor and P-channel transistor of each cell has a hooked shape in which there is a first bent part (11a) bending in one direction at an upper portion and a second bent part (11b) bending in the other direction at a lower portion.

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 24-33 are rejected under 35 U.S.C. 103(a) as being unpatentable over Nagai et al. (US 6,114,767 B1) in view of the Applicant's Prior Art Figure 31 (APAF).

Nagai et al. does not specifically disclose the power supply and master patterns of the device but is such items are necessary for the function of the semiconductor and well known in the art. However, the APAF 31 also shows a power supply (7), a master pattern, and another interconnect pattern different from the interconnect pattern. The another interconnect patter exists between the N-channel transistor and the master pattern and extends along a perpendicular direction relative to a boundary between two

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transistors. The another interconnect pattern is disconnected from the transistors and formed in an uppermost interconnect layer. The interconnect is also mutually connected with an interconnect pattern of another CMOS cell, the CMOS cell adjacent to the another CMOS cell. Two or more interconnect patterns are electrically connected by a higher interconnect pattern located in a layer higher than the interconnect pattern. Therefore it would have been obvious to one of ordinary skill in the art at the time the invention was made to modify the interconnect pattern of Nagai by using power supply and alternate interconnect patterns as shown by the APAF to form connections to the various basic cells in the semiconductor device.

Nagai et al. and the APAF show all of the elements of the claims except the method of fabricating the gate array. A "product by process" claim is directed to the product per se, no matter how actually made, In re Hirao, 190 USPQ 15 at 17(footnote 3). See also in re Brown, 173 USPQ 685: In re Luck, 177 USPQ 523; In re Fessmann, 180 USPQ 324: In re Avery, 186 USPQ 116 in re Wertheim, 191 USPQ 90 (209 USPQ 254 does not deal with this issue); and In re Marosi et al, 218 USPQ 289 final product per se which must be determined in a "product by, all of" claim, and not the patentability of the process, and that an old or obvious product, whether claimed in "product by process" claims or not. Note that Applicant has the burden of proof in such cases, as the above case law makes clear. "Even though product-by- process claims are limited by and defined by the process, determination of patentability is based upon the product itself. The patentability of a product does not depend on its method of production. If the product in product-by-process claim is the same as or obvious from a product of the

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prior art, the claim is unpatentable even though the prior product is made by a different process." In re Thorpe, 227 USPQ 964, 966 (Fed. Cir. 1985)(citations omitted).

Allowable Subject Matter

Claims 34-40 are allowed.

The following is an examiner's statement of reasons for allowance: the prior art references, alone or in combination, do not show a CMOS basic cell comprising a gate of one of N and P channel transistors having a hooked shape including a first bent part at one upper end portion and second bent part in an opposite side direction at a lower end and a diffusion region having a hooked shape having a first bent part at an upper portion and a second bent part in an opposite side direction at a lower portion wherein the upper portion of the gate is bent oppositely to the upper portion of the diffusion region.

Any comments considered necessary by applicant must be submitted no later than the payment of the issue fee and, to avoid processing delays, should preferably accompany the issue fee. Such submissions should be clearly labeled "Comments on Statement of Reasons for Allowance."

Response to Arguments

Applicant's arguments with respect to claims 22-33 have been considered but are moot in view of the new ground(s) of rejection.

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Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Matthew E. Warren whose telephone number is (703) 305-0760. The examiner can normally be reached on Mon-Thurs, and alternating Fri, 9:00-5:00.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Eddie Lee can be reached on (703) 308-1690. The fax phone numbers for the organization where this application or proceeding is assigned are (703) 305-3432 for regular communications and (703) 308-7722 for After Final communications.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is (703) 308-0956.

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May 5, 2003

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